

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of)
)
	Toshiki Makimoto, et al.)
)
Serial No.:	10/516,380) Art Unit
) 2818
Filing Date:	November 30, 2004)
)
Confirmation No.:	2860)
)
For:	P-TYPE NITRIDE SEMICONDUCTOR)
	STRUCTURE AND BIPOLAR TRANSISTOR)
)
Examiner:	Tram Hoang Nguyen)

AMENDMENT "B" AND RESPONSE TO FINAL OFFICE ACTION

Commissioner for Patents
PO Box 1450
Alexandria, Virginia 22313-1450

Examiner:

Applicant submits this paper in response to the Final Office Action mailed July 11, 2007 and in conjunction with a Request for Continued Examination (RCE). Reconsideration is respectfully requested in view of the following remarks:

Amendments to the Claims begin on page 2 of this paper.

Remarks begin on page 5 of this paper.